

Maximum Ratings @ TA = 25°C unless otherwise stated

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	30	V
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	$T_A = 25$ °C $T_A = 70$ °C	I _D	3.5 2.7	Α
	t<10s	$T_A = 25$ °C $T_A = 70$ °C	I _D	4.3 3.3	А
Continuous Drain Current (Note 6) V 4.5V	Steady State	$T_A = 25$ °C $T_A = 70$ °C	I _D	2.8 2.1	Α
Continuous Drain Current (Note 6) V _{GS} = 4.5V	t<10s	$T_A = 25$ °C $T_A = 70$ °C	I _D	3.4 2.6	А
Pulsed Drain Current (10μs pulse, duty cycle = 1%)			I _{DM}	25	Α
Maximum Body Diode Forward Current (Note 5)			Is	1.5	Α

Thermal Characteristics @ T_A = 25°C unless otherwise stated

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)		P_{D}	0.84	W
Thermal Decistores, Junction to Ambient (Note 5)	Steady state	<u> </u>	155	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	109	
Total Power Dissipation (Note 6)		P_{D}	1.27	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	0	102	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	72	
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	34	
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

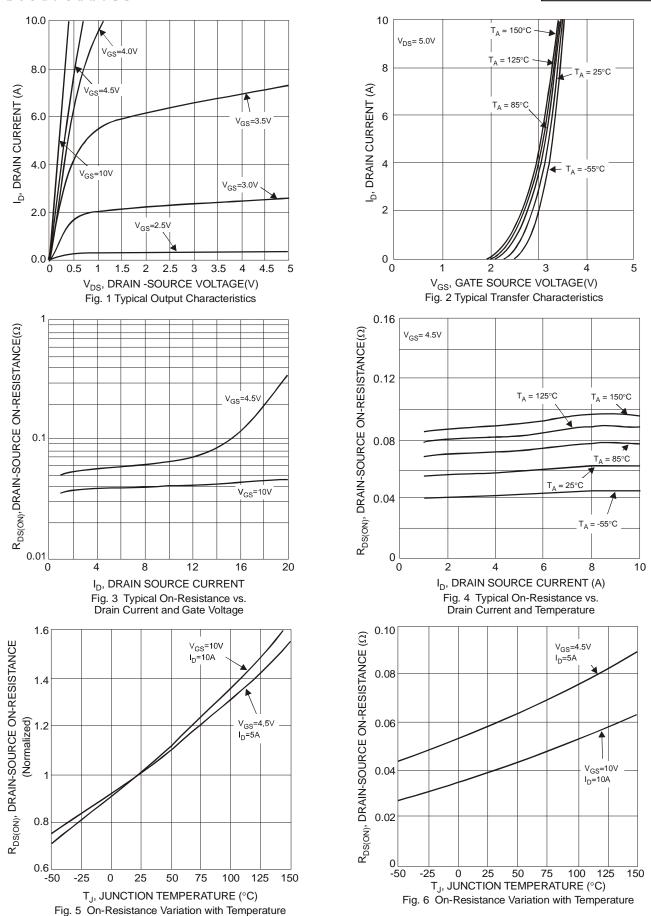
Electrical Characteristics @ TA = 25°C unless otherwise stated

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						•	
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	1	-	1.0	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)	ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(th)}	1.3	1.8	2.2	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	D		35	60	mΩ	$V_{GS} = 10V, I_D = 3.1A$	
Static Drain-Source On-Resistance	R _{DS} (ON)	-	54	100		$V_{GS} = 4.5V, I_D = 2A$	
Forward Transfer Admittance	Y _{fs}	-	4	-	S	$V_{DS} = 5V, I_{D} = 3.1A$	
Diode Forward Voltage	V_{SD}	-	0.8	1	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	-	305	-		V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss	-	40	-	pF		
Reverse Transfer Capacitance	Crss	-	40	-			
Gate Resistance	R_g	-	1.4	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	-	4.1	-		$V_{DS} = 15V$, $V_{GS} = 4.5V$, $I_{D} = 3.1A$	
Total Gate Charge	Q_{g}	-	9.0	-	nC		
Gate-Source Charge	Q _{gs}	-	1.2	-	nc nc	$V_{DS} = 15V$, $V_{GS} = 10V$, $I_D = 3.1A$	
Gate-Drain Charge	Q_{gd}	-	1.5	-			
Turn-On Delay Time	t _{D(on)}	-	2.6	-		$V_{GS} = 10V, V_{DS} = 15V,$ $R_G = 3\Omega, R_L = 4.7\Omega$	
Turn-On Rise Time	tr	-	4.6	-			
Turn-Off Delay Time	t _{D(off)}	-	13.1	-	ns		
Turn-Off Fall Time	t _f	-	2.5	-			

Notes:

- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.







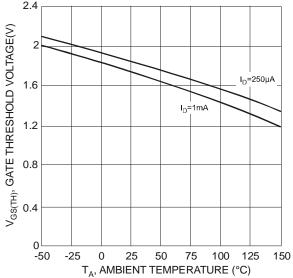
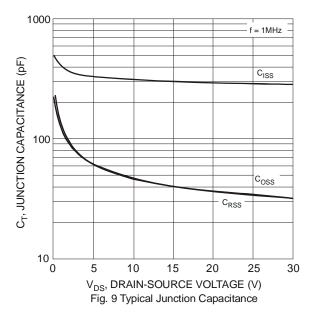
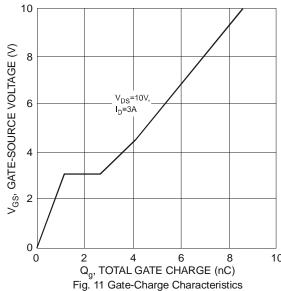
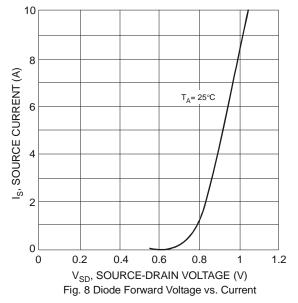


Fig. 7 Gate Threshold Variation vs. Ambient Temperature







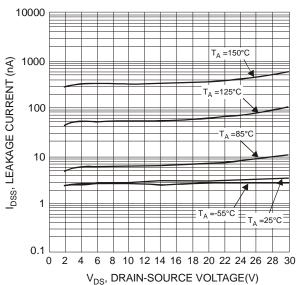


Fig. 10 Typical Drain-Source Leakage Current vs. Voltage

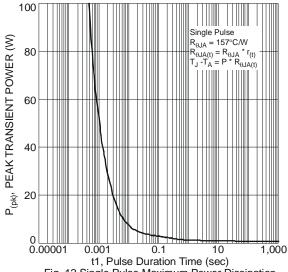
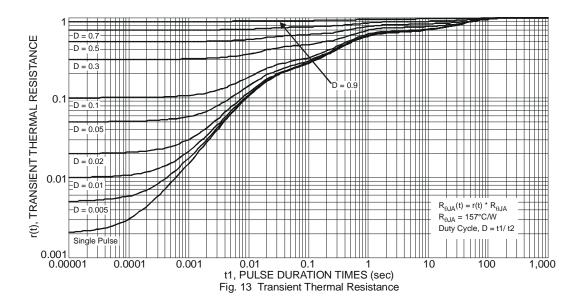
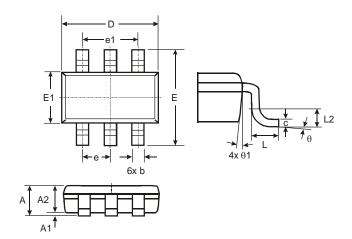


Fig. 12 Single Pulse Maximum Power Dissipation



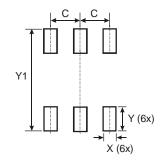


Package Outline Dimensions



TSOT26						
Dim	Min	Max	Тур			
Α	_	1.00	_			
A1	0.01	0.10	_			
A2	0.84	0.90	_			
D	_	_	2.90			
Е	_	_	2.80			
E1	_	_	1.60			
b	0.30	0.45	_			
С	0.12	0.20	_			
е	_	-	0.95			
e1	_	_	1.90			
L	0.30	0.50				
L2	-	_	0.25			
θ	0°	8°	4°			
θ1	4°	12°	_			
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
С	0.950
Х	0.700
Y	1.000
Y1	3.199



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